

GAME CHANGER

Sunflare Introduces Capture4 solar technology, the first high-precision, cell-by-cell manufacturing process for exceptional performance and durability. The environmentally cleanest method of massproducing solar panels in the world.

MORE ELECTRICITY IN REAL-WORLD CONDITIONS

Better at Dawn and Dusk

Sunflare delivers more energy than c-Si in low light condition.

Better in Poor Weather

Cloudy days, fog, and high humidity, no problem.

Won't Crack Under Pressure

Traditional cells are made with silicon, which is brittle. Flexing creates cracking in the cell. These cracks reduce the energy output over time. Sunflare has a flexible stainless steel substrate with a mere micron of chemical the combination eliminates micro-cracking.

Easy Installation

Fast and low cost installation. Adheres with best quality double sided tape and no roof penetrations.

Shading

Sunflare modules have bypass diodes on each individual cell. This means that when a cell is being shaded, only that individual cell will be inactive. Therefore, the power output of the module will be proportional to the amount of the module being shaded, i.e. if half of the module is shaded, you should expect half of the rated power output.

GUARANTEED RELIABILITY FOR 25 YEARS

90% efficiency output for first 10 years 80% efficiency output 11-25 years



Lightweight

75% lighter than c-Si panels.



Thin

95% thinner than c-Si panels.



Flexible

The .127mm stainless steel substrate allows for generous curvature.



Durable

Withstands high impact. Impervious to heat, wind and cold. Will not crack.



ELECTRICAL DATA

Standard Test Conditions:

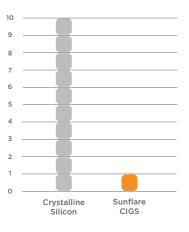
Peak Power (+3/-3%)	Pmax	165W	170W	175W	180W	185W
Aperture Efficiency		13.3%	13.7%	14.1%	14.5%	15.0%
Peak Power Voltage	Vmpp	27.5V	27.4V	28.2V	28.7V	28.3V
Peak Power Current	Impp	6.0A	6.2A	6.2A	6.3A	6.5A
Open Circuit Voltage	Voc	35.4V	35.7V	36.0V	36.4V	36.6V
Short Circuit Current	Isc	7.3A	7.4A	7.4A	7.4A	7.5A

Maximum System VoltageUL/IEC1000VTemperature Coefficient Power-0.35 %/°CTemperature Coefficient Voltage-0.25 %/°CTemperature Coefficient Current+0.03%/°CNOCT52.1°CSeries Fuse Rating12A

Grounding Not Required

Environmentally Cleanest

1/10 Carbon Footprint of Silicon modules



Source: Life cycle assessment of CIGS solar modules and future integration in Zbee 2017-12-18 Sandra Roos, Magdalena Juntikka. Study reviewed and approved by Swedish independent third-party institute Miljögiraff AB.

MECHANICAL DATA

Solar Cells SUN² CIGS

Junction Box IP-65, MC4 compatible

Frame No frame Weight 5kg (11 lbs)

Hot Spot Protection Bypass diode per cell

Top Sheet Material ETFE
Wind Up-Force Load 110lb/sf

Module Thickness

1.7 mm

Temperature F (C)

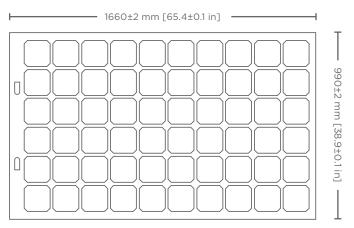
-40° F to + 185° F (-40°C to +85°C)

Impact Resistance

25mm (1 in) diameter hail at 52 mph (23 m/s)

MODULE SPECS

Module Dimension



TESTS AND CERTIFICATIONS

Standard Tests	C € UL 1703 IEC 61215, IEC 61730
Management	ISO 9001:2015,
System Certs	ISO 14001:2015



^{*}Irradiance of 1000W/mxm, AM 1.5 and cell temperature 25 degree C